

Fig. 1

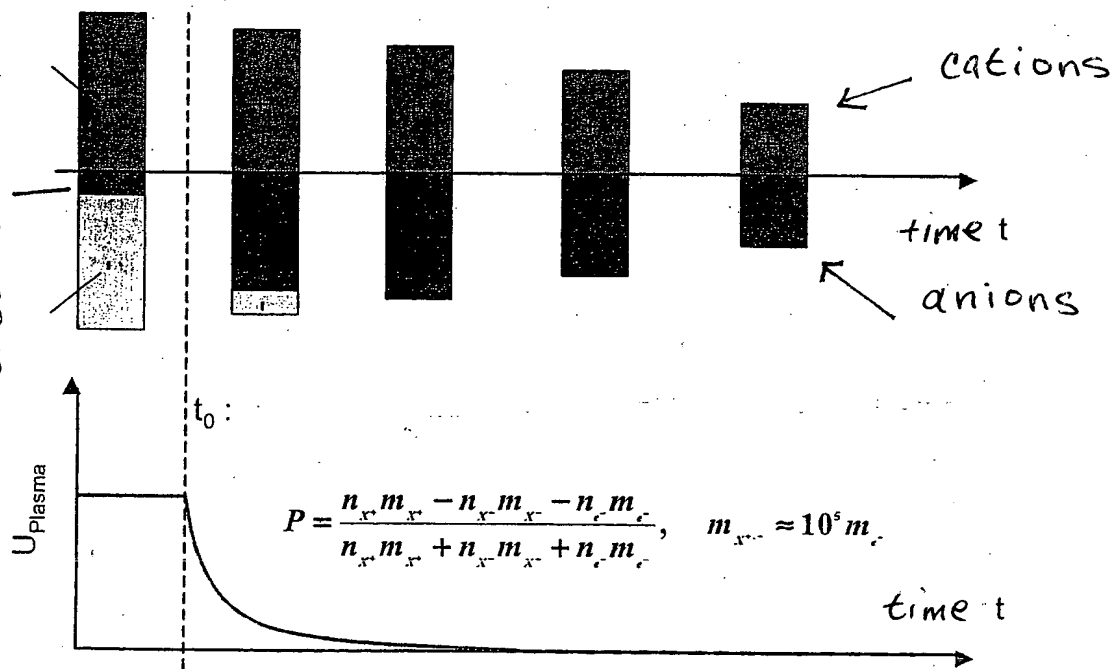


Fig. 2

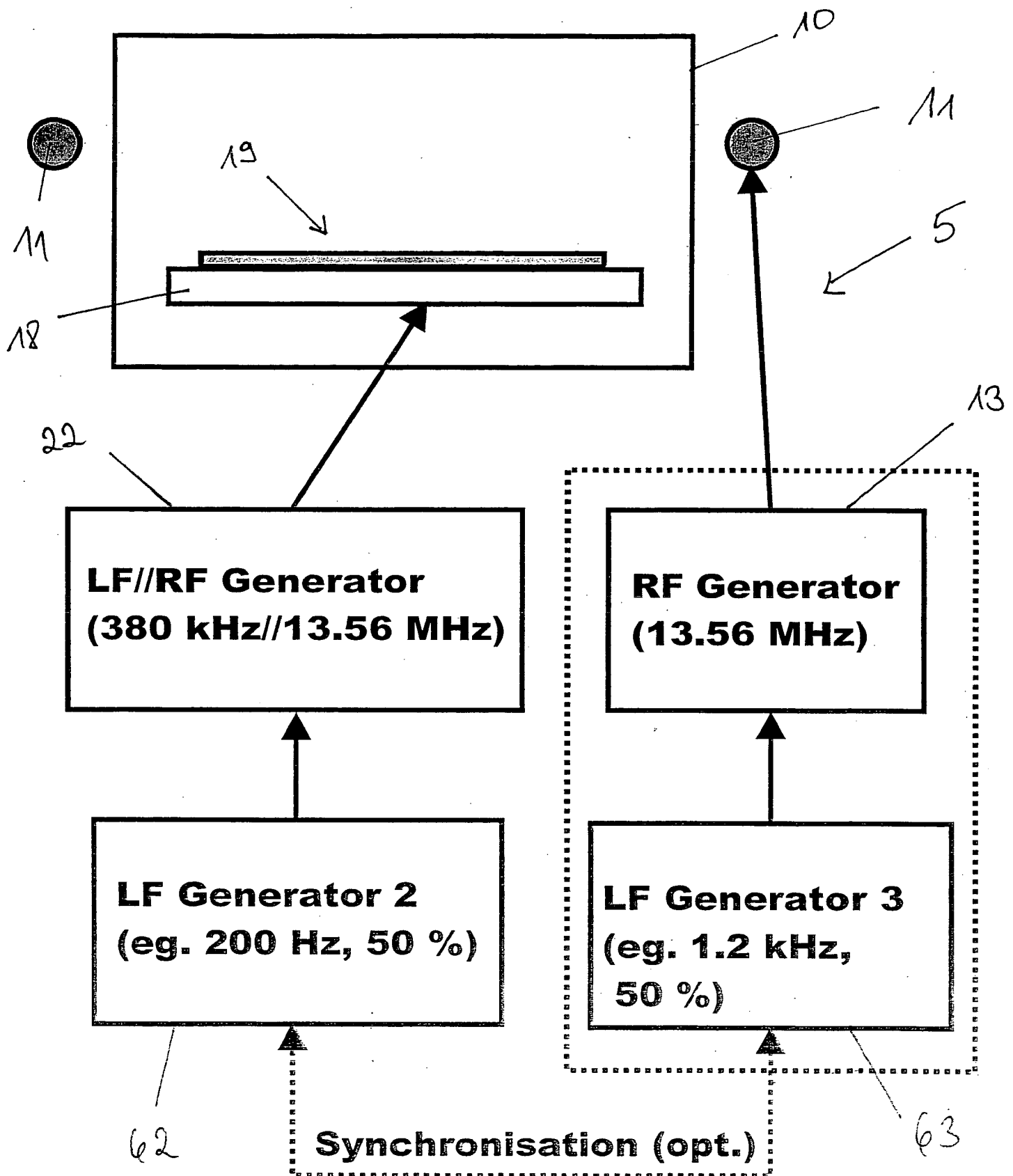


Fig. 3

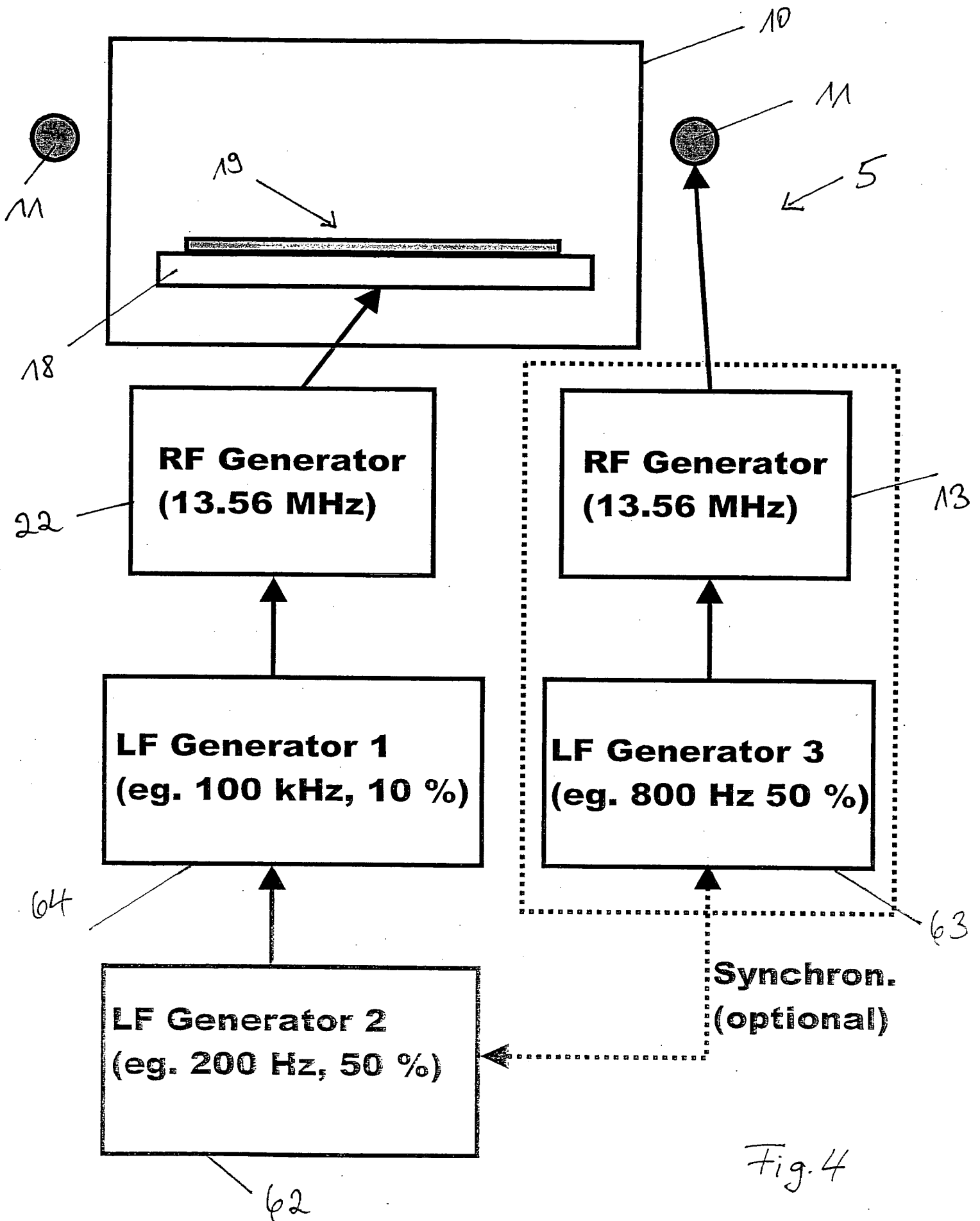
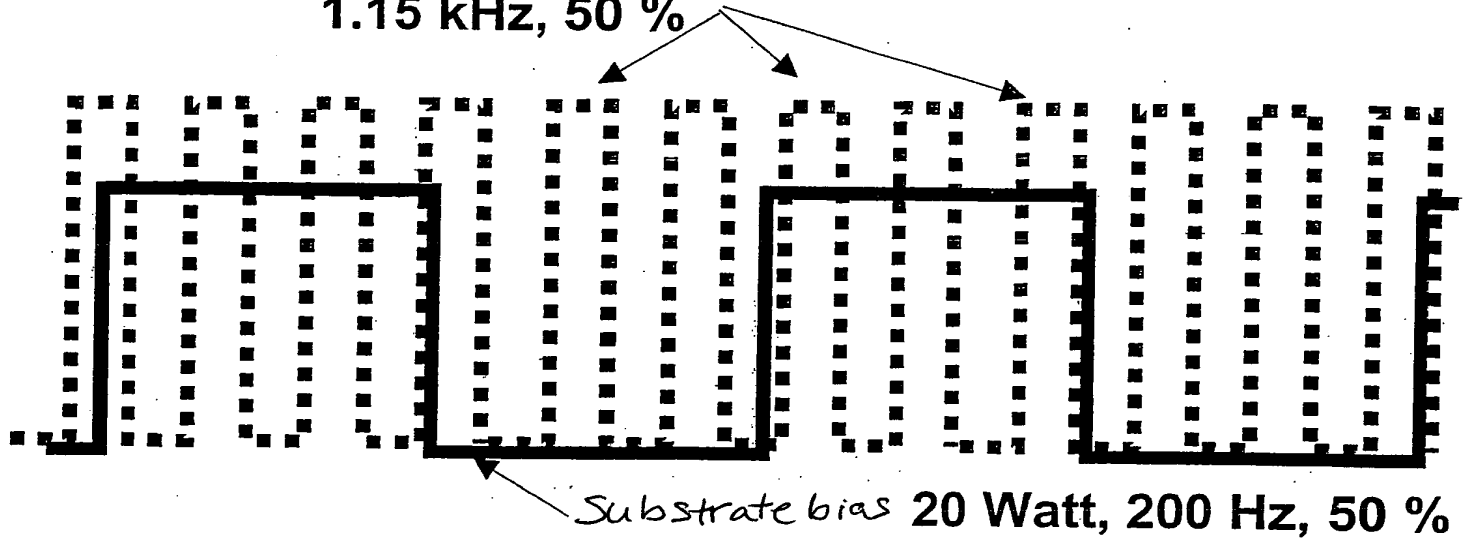


Fig. 4

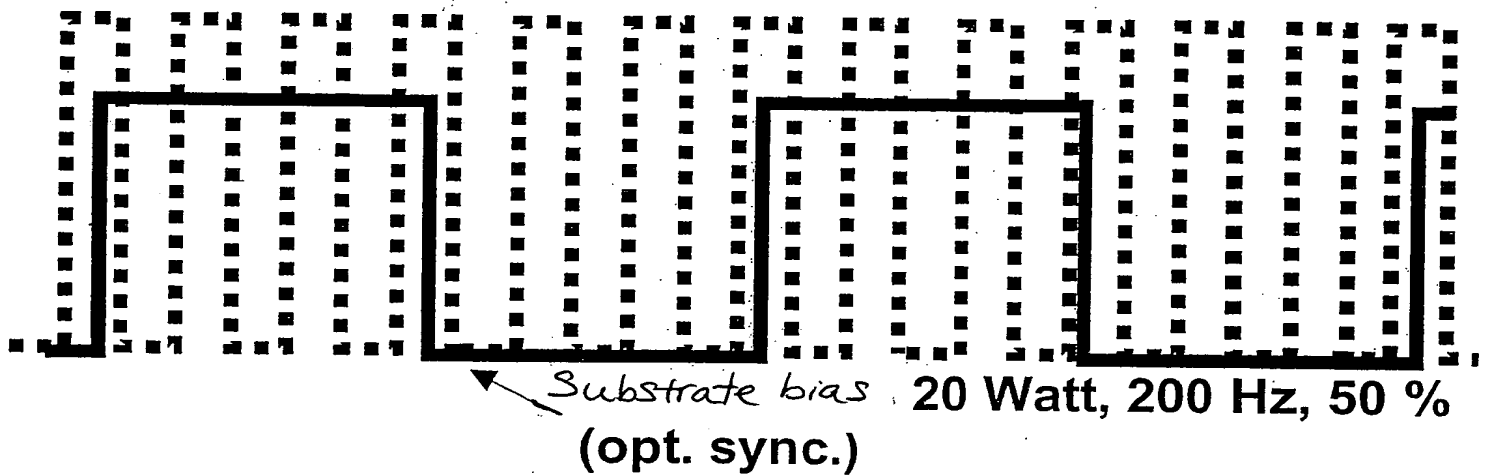
4111

K.41619-1

Plasma power, (ICP-Power): e.g. 3 kWatt,
1.15 kHz, 50 %



Plasma power, (ICP-Power): e.g. 3 kWatt,
1.20 kHz, 50 %



Plasma power (ICP-Power): e.g. 3 kWatt,
800 Hz, 50 %

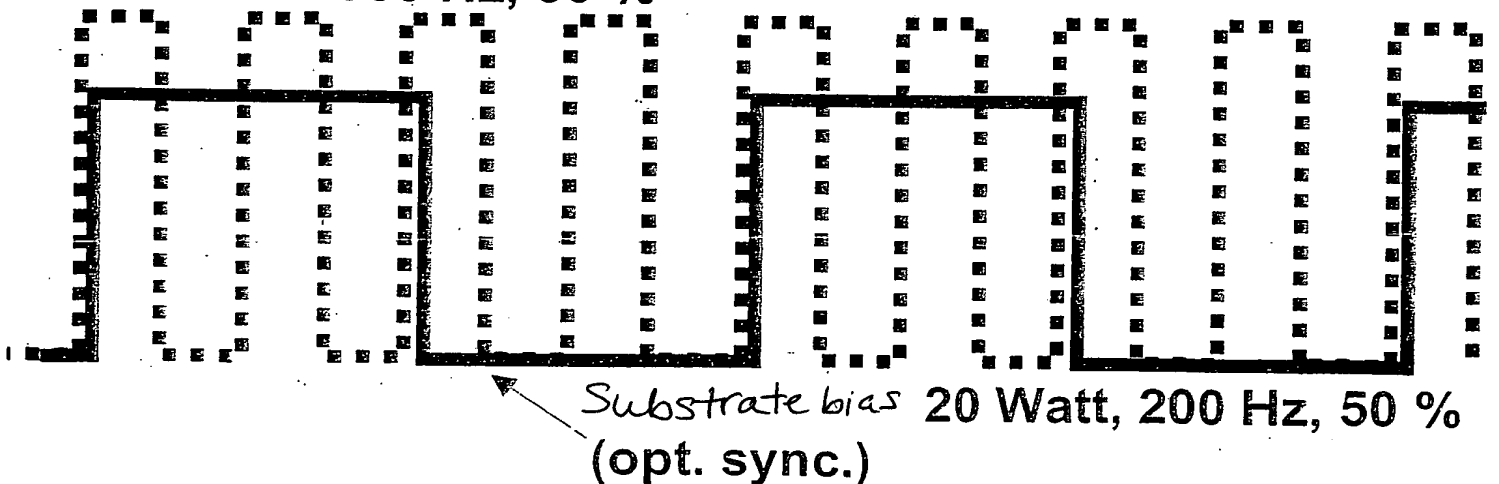


Fig. 5

5111

R. 41619-1

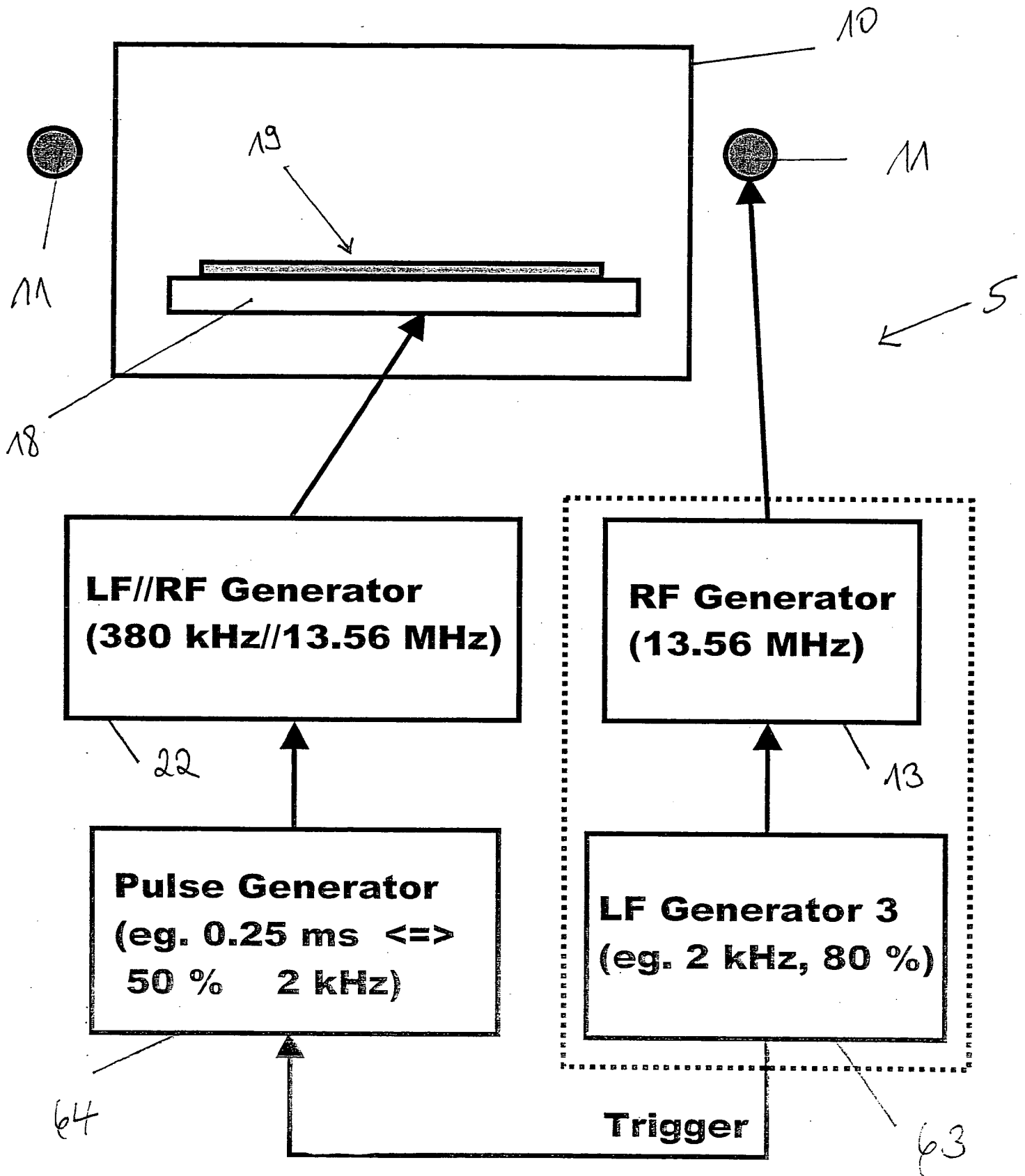
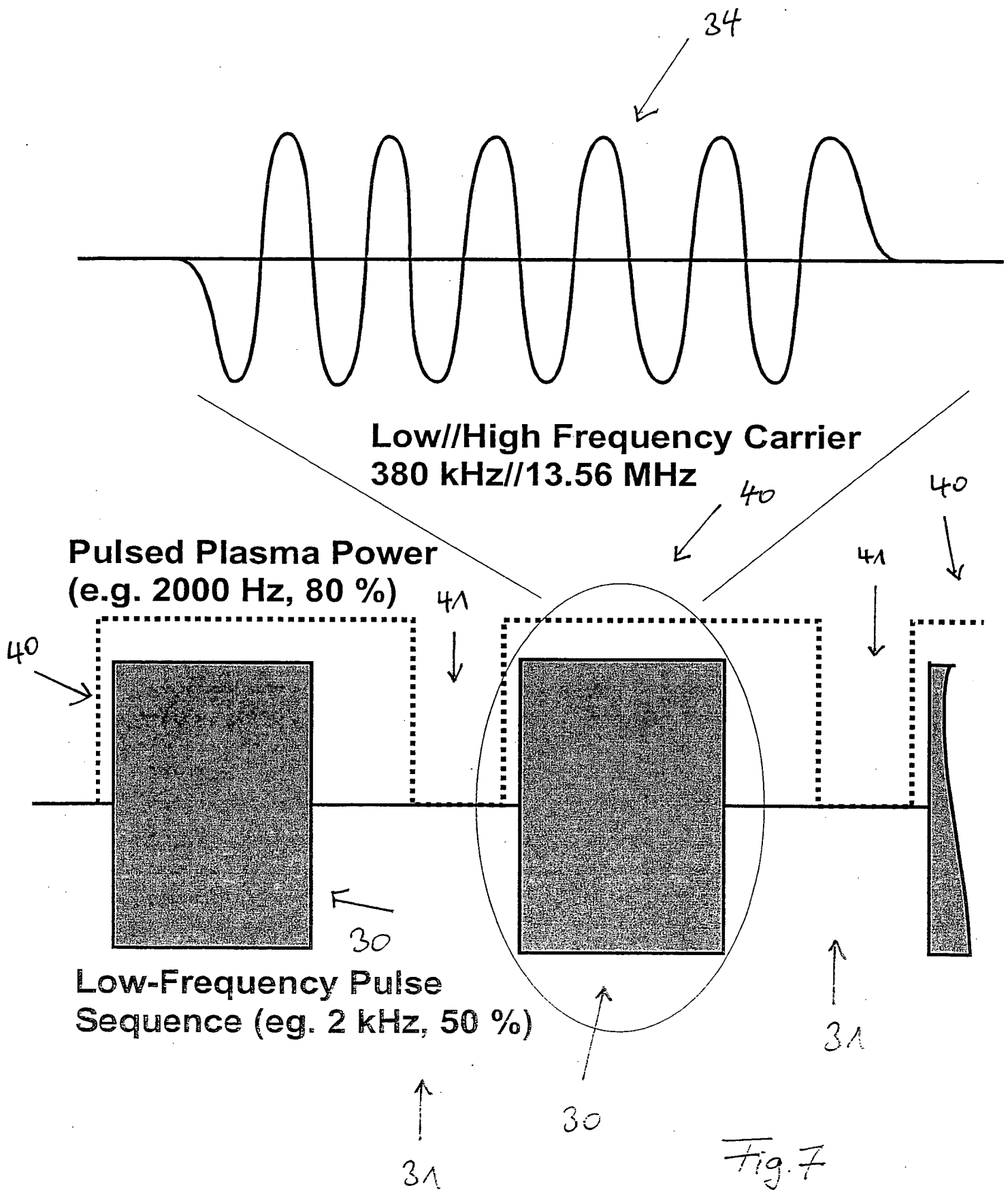
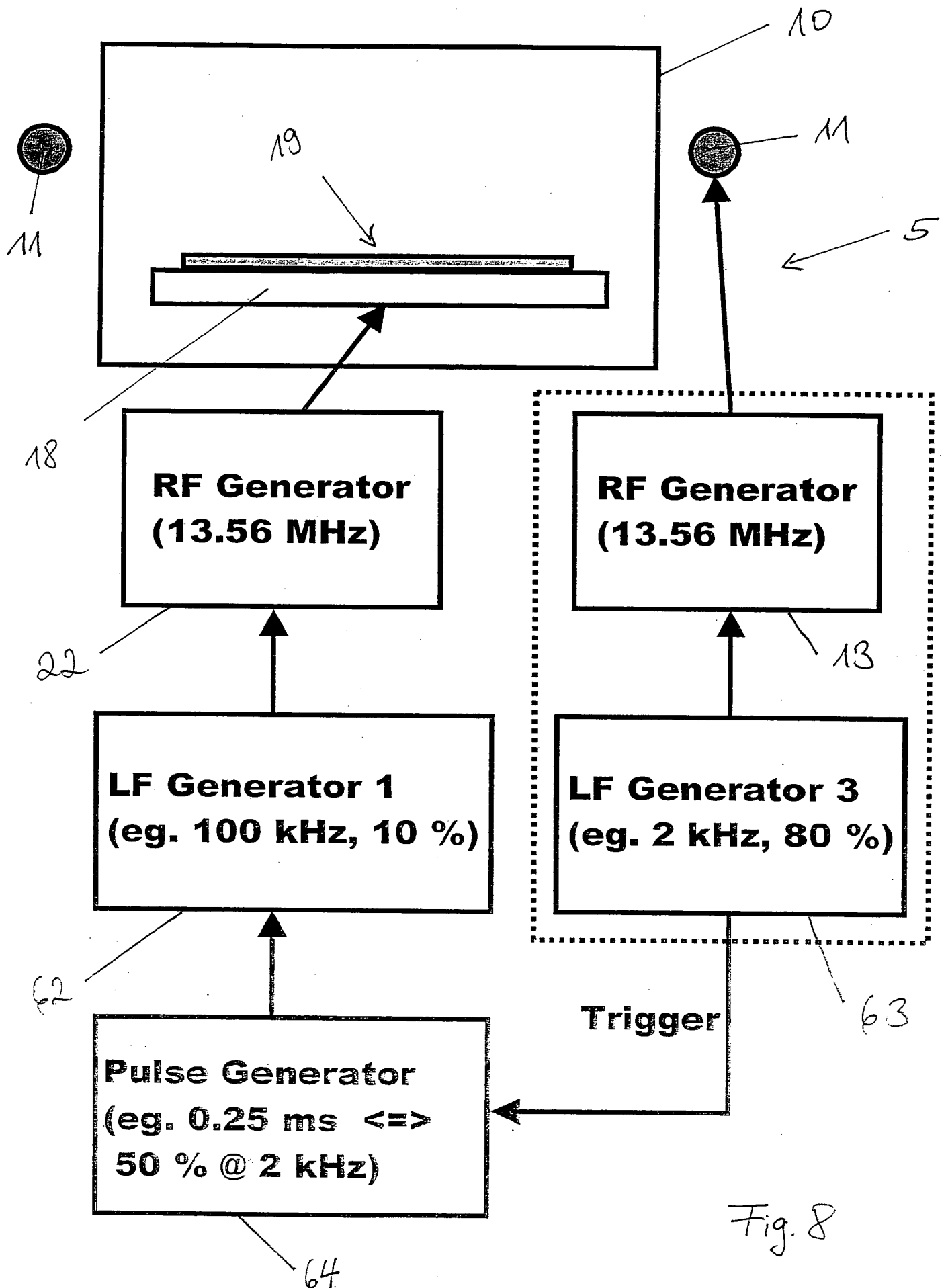


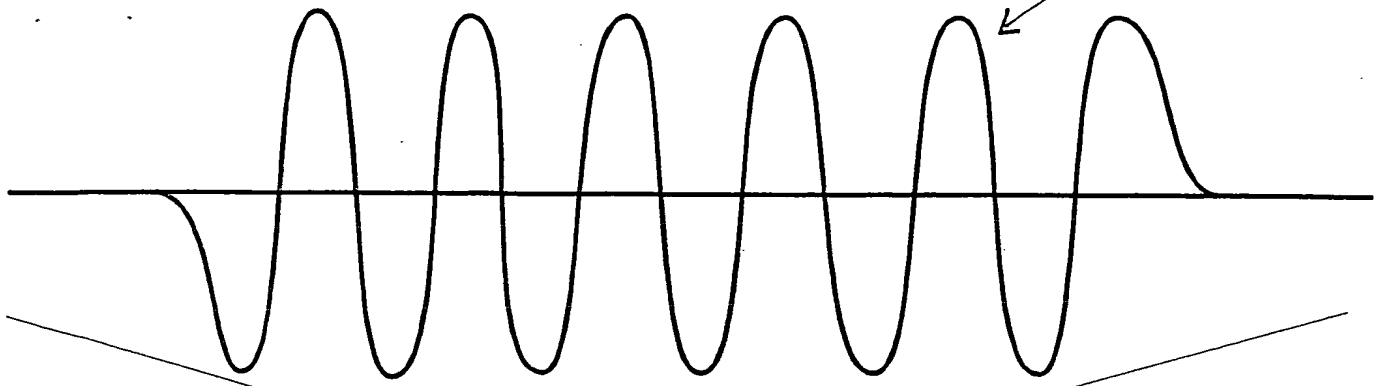
Fig. 6



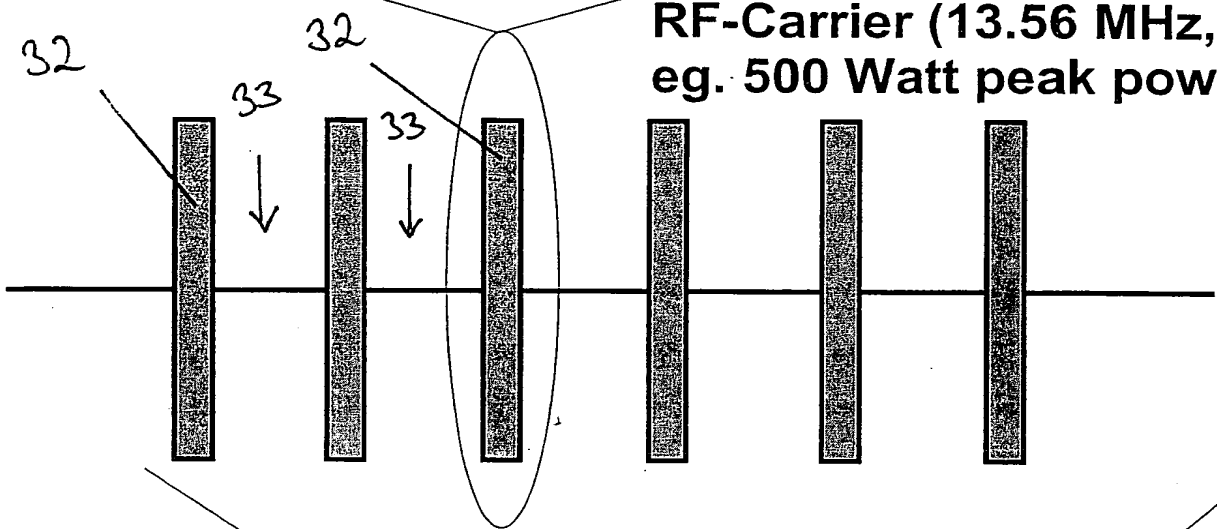


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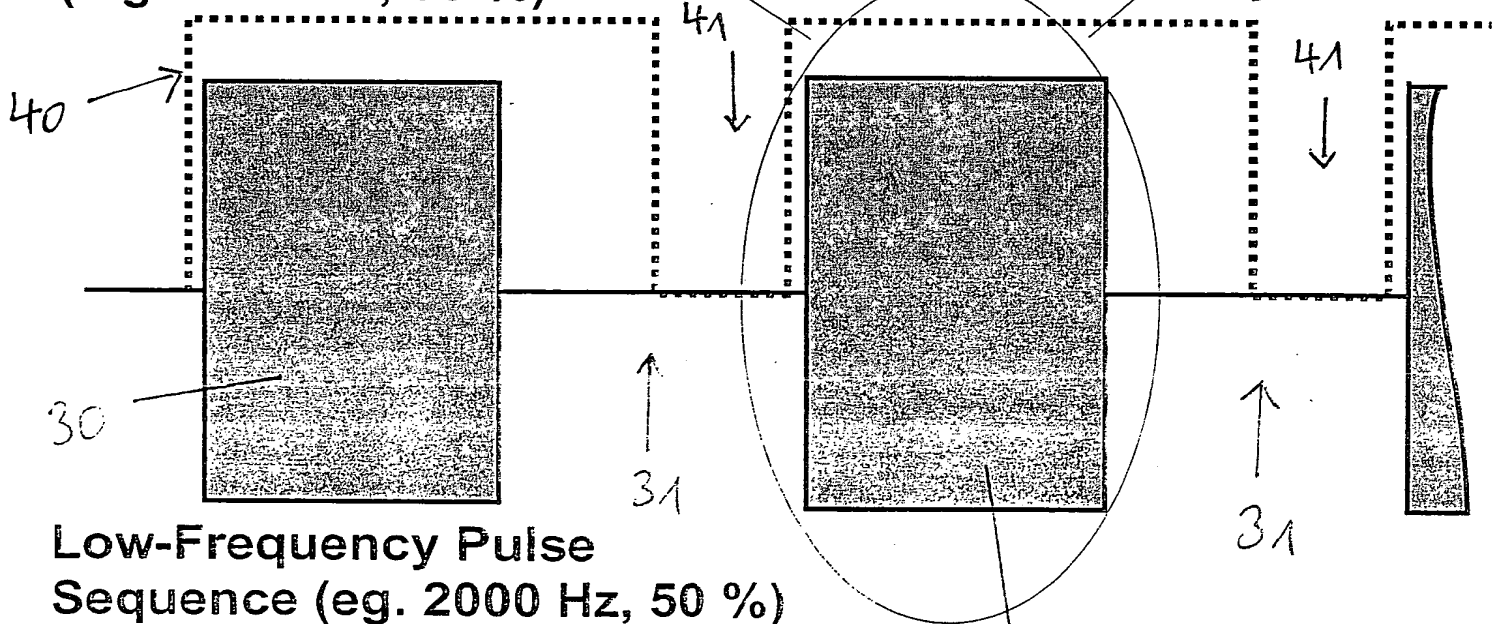


RF-Carrier (13.56 MHz,
eg. 500 Watt peak power)



High-Frequency Pulse Flow
(eg. 100 kHz, 10 %)

Pulsed Plasma Power
(e.g. 2000 Hz, 80 %)



Low-Frequency Pulse
Sequence (eg. 2000 Hz, 50 %)

30

Fig. 9

9111

R-41619-1

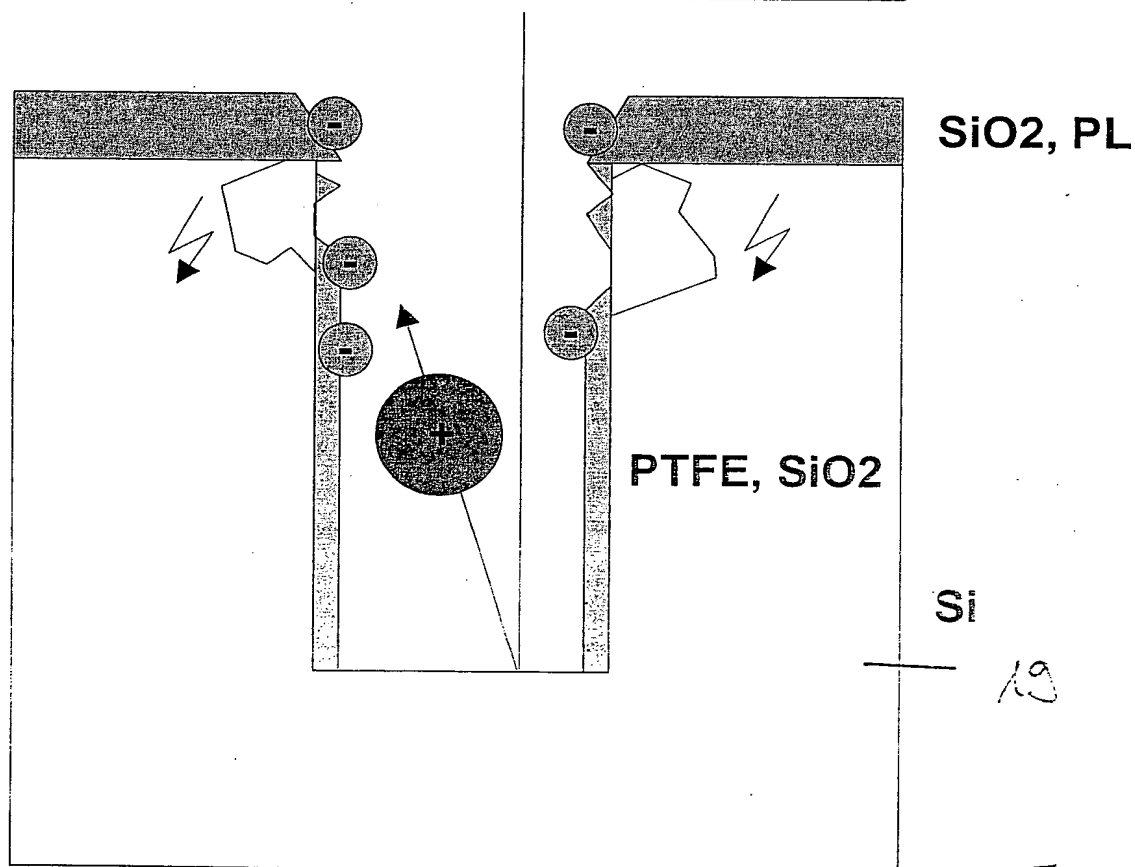
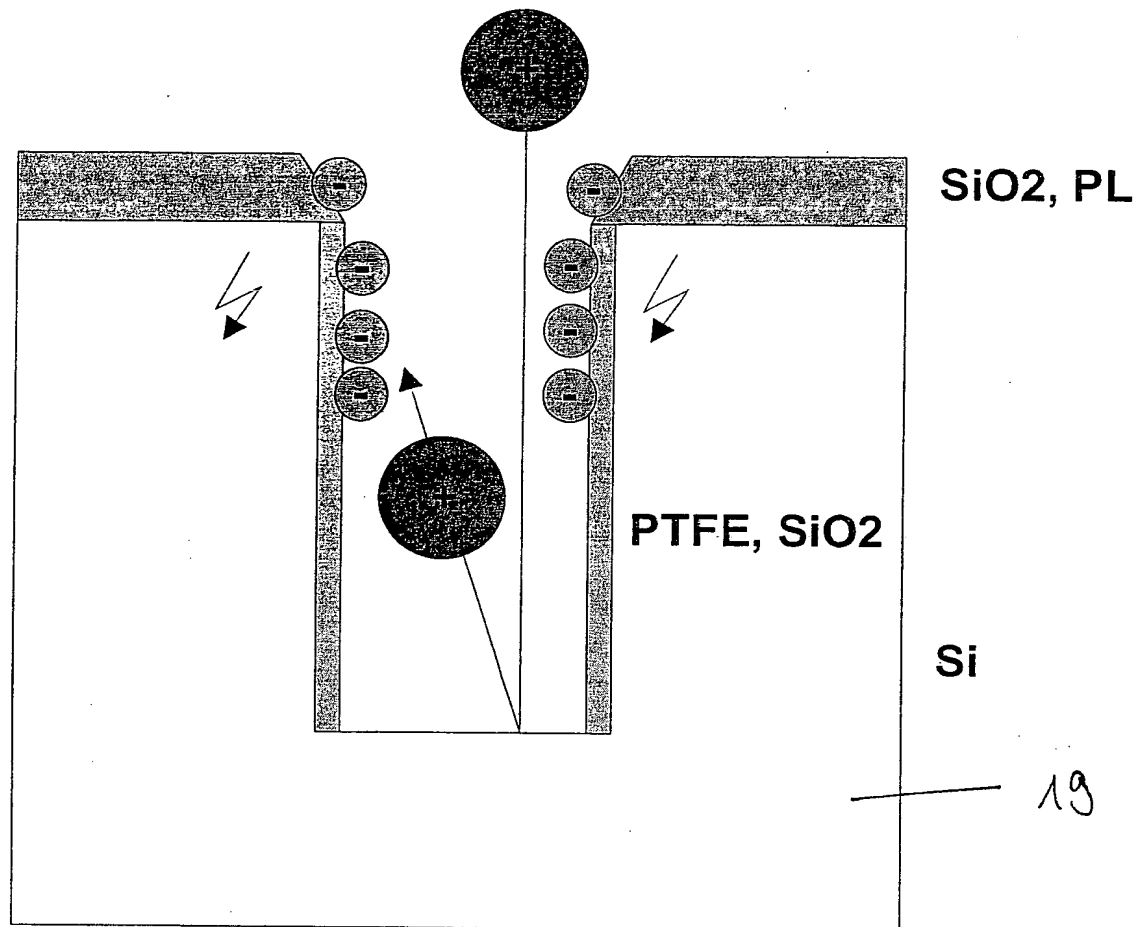


Fig. 10

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R. 41629-1

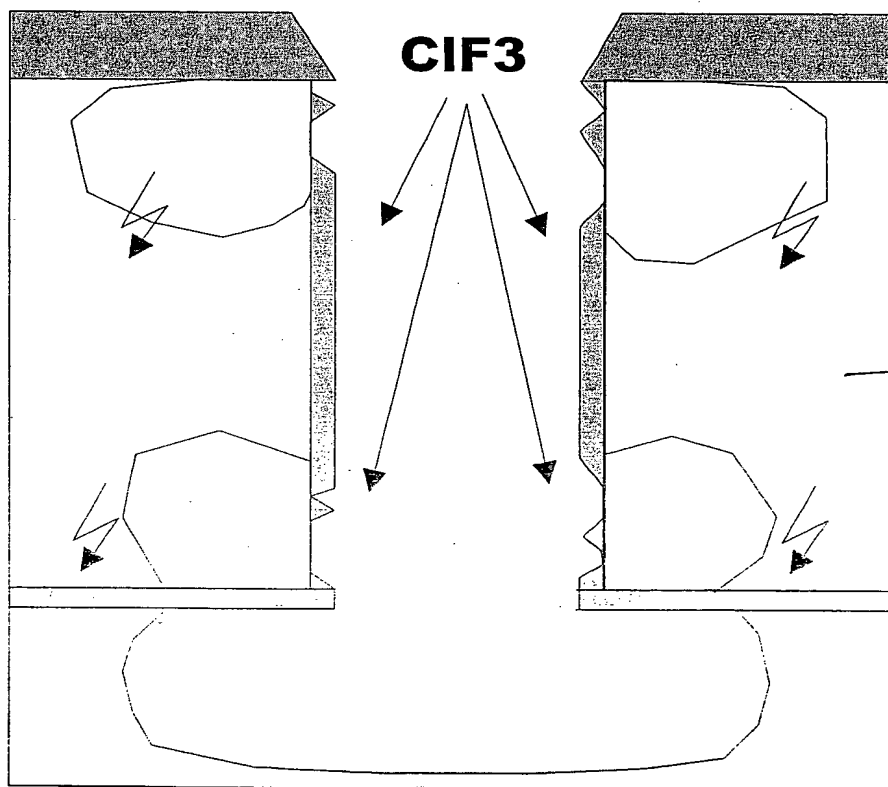
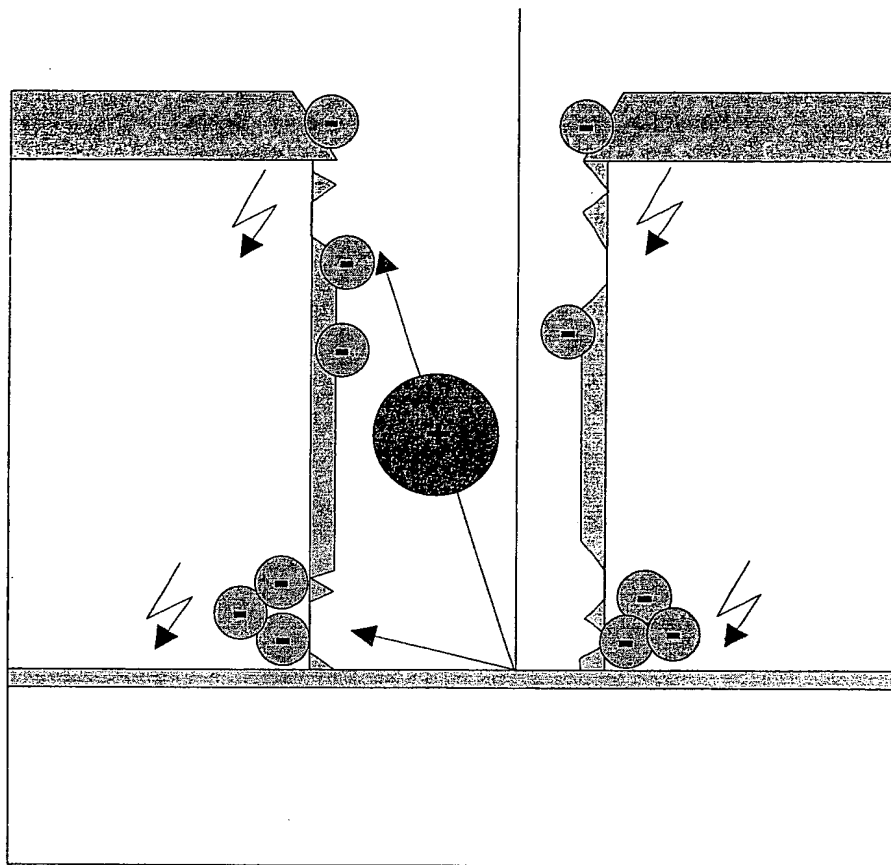


Fig. 11

11111

R.41619-1

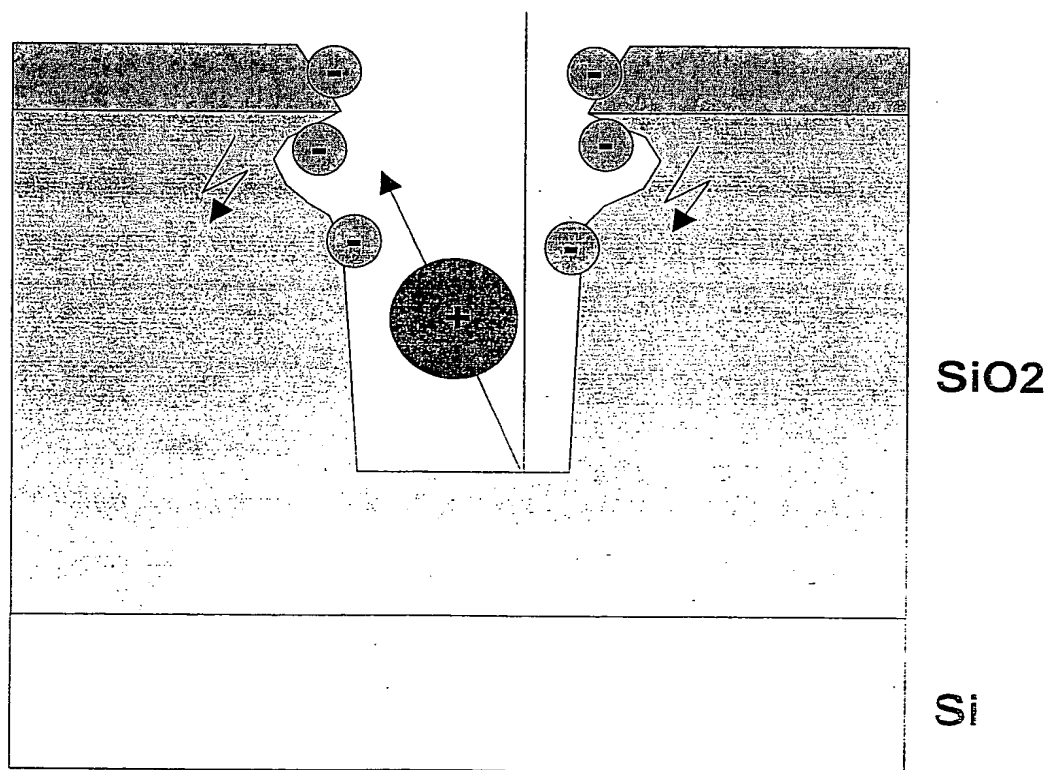
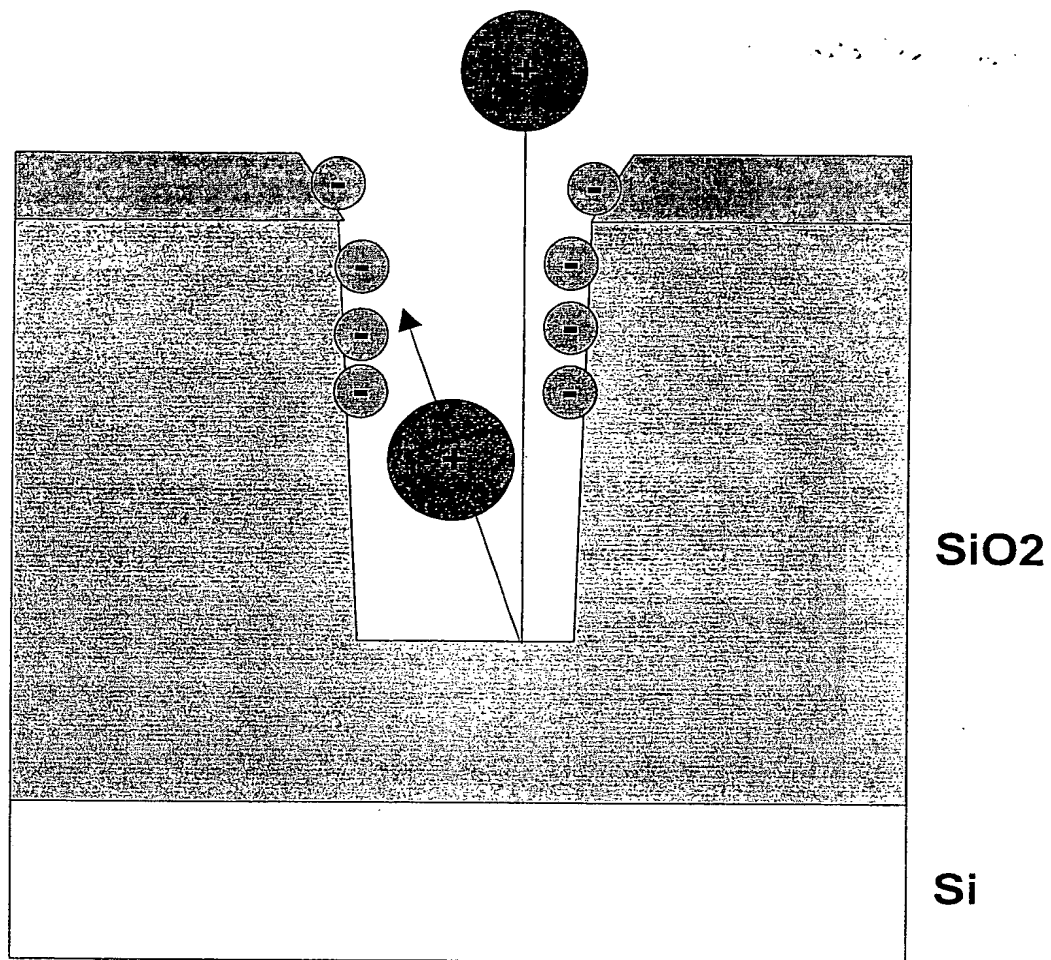


Fig. 12